

isc N-Channel MOSFET Transistor

IXTA180N10T

• FEATURES

- Static drain-source on-resistance:
 $R_{DS(on)} \leq 6.4\text{m}\Omega @ V_{GS}=10\text{V}$
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATION

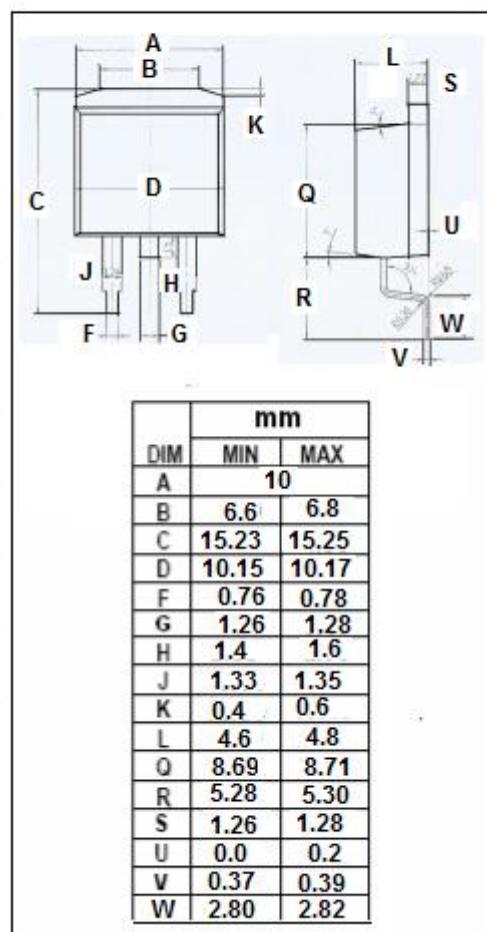
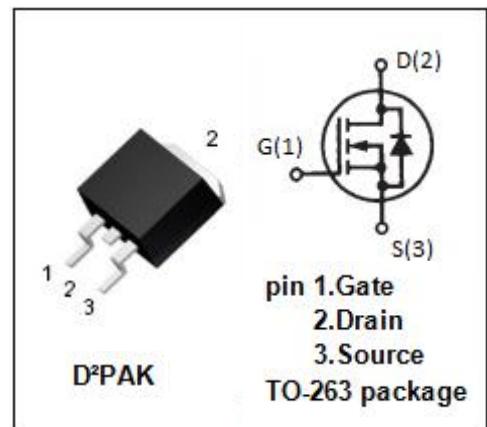
- DC/DC Converters
- High Speed Power Switching Applications

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	100	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	180	A
I_{DM}	Drain Current-Single Pulsed	450	A
P_D	Total Dissipation @ $T_c=25^\circ\text{C}$	480	W
T_j	Operating Junction Temperature	-55~175	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~175	$^\circ\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Junction-to-case thermal resistance	0.31	$^\circ\text{C}/\text{W}$



isc N-Channel MOSFET Transistor**IXTA180N10T****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{ID}=250 \mu\text{A}$	100		V
$\text{V}_{\text{GS(th)}}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}; \text{ID}=250 \mu\text{A}$	2.0	4.0	V
$\text{R}_{\text{DS(on)}}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}=10\text{V}; \text{I}_D=25\text{A}$		6.4	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$\text{V}_{\text{GS}}= \pm 20\text{V}; \text{V}_{\text{DS}}=0\text{V}$		± 100	nA
I_{DSS}	Drain-Source Leakage Current	$\text{V}_{\text{DS}}= \text{V}_{\text{DSS}}; \text{V}_{\text{GS}}= 0\text{V}$		5	μA
		$\text{V}_{\text{DS}}= \text{V}_{\text{DSS}}; \text{V}_{\text{GS}}= 0\text{V}; \text{T}_J= 150^\circ\text{C}$		100	
V_{SD}	Diode forward voltage	$\text{I}_F= 25\text{A}; \text{V}_{\text{GS}}= 0\text{V}$		0.95	V

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